

RoHS Compliant Product
A suffix of "-C" specifies halogen & lead-free

DESCRIPTION

The SMS3401A provide the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness. The SOT-23 package is universally preferred for all commercial-industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

FEATURES

- Lower Gate Charge
- Simple Drive Requirement
- Fast Switching Characteristic

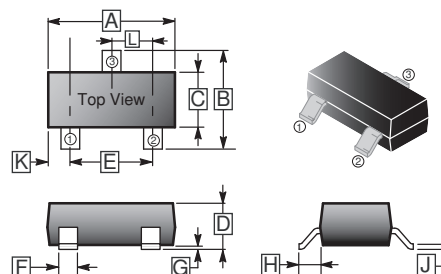
MARKING

R1_A

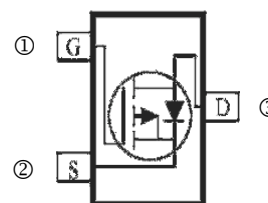
PACKAGE INFORMATION

Package	MPQ	Leader Size
SOT-23	3K	7 inch

SOT-23



REF.	Millimeter		REF.	Millimeter	
	Min.	Max.		Min.	Max.
A	2.70	3.10	G	0.09	0.18
B	2.10	2.65	H	0.35	0.65
C	1.20	1.40	J	0.08	0.20
D	0.89	1.17	K	0.6 REF.	
E	1.78	2.04	L	0.95 BSC.	
F	0.30	0.50			



ABSOLUTE MAXIMUM RATINGS (T_A=25°C unless otherwise specified)

Parameter	Symbol	Rating	Unit
Drain-Source Voltage	V _{DS}	-30	V
Gate-Source Voltage	V _{GS}	±12	V
Continuous Drain Current	I _D	-4.2	A
Maximum Power Dissipation	P _D	400	mW
Thermal Resistance Junction-Ambient (t<5s)	R _{θJA}	313	°C / W
Operating Junction & Storage Temperature	T _J , T _{STG}	150, -55~150	°C

ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	-30	-	-	V	$V_{GS}=0, I_D = -250\mu\text{A}$
Gate-Threshold Voltage	$V_{GS(th)}$	-0.7	-	-1.3	V	$V_{DS}=V_{GS}, I_D = -250\mu\text{A}$
Gate-Source Leakage Current	I_{GSS}	-	-	± 100	nA	$V_{GS} = \pm 12\text{V}, V_{DS}=0$
Drain-Source Leakage Current	I_{DSS}	-	-	-1	μA	$V_{DS} = -24\text{V}, V_{GS}=0$
Forward Transconductance ¹	g_{fs}	7	-	-	S	$V_{DS} = -5\text{V}, I_D = -5\text{A}$
Static Drain-Source On-Resistance ¹	$R_{DS(ON)}$	-	-	60	m Ω	$V_{GS} = -10\text{V}, I_D = -4.2\text{A}$
		-	-	70		$V_{GS} = -4.5\text{V}, I_D = -4\text{A}$
		-	-	85		$V_{GS} = -2.5\text{V}, I_D = -1\text{A}$
Dynamic Parameters ²						
Input Capacitance	C_{iss}	-	1050	-	pF	$V_{GS}=0$ $V_{DS} = -15\text{V}$ $f = 1.0\text{MHz}$
Output Capacitance	C_{oss}	-	127	-		
Reverse Transfer Capacitance	C_{rss}	-	85	-		
Turn-on Delay Time	$T_{d(on)}$	-	6.5	-	nS	$V_{GS} = -10\text{V}$ $V_{DS} = -15\text{V}$ $R_{GEN}=6\Omega$ $R_L=3.6\Omega$
Rise Time	T_r	-	3.5	-		
Turn-off Delay Time	$T_{d(off)}$	-	40	-		
Fall Time	T_f	-	13	-		
Source-Drain Diode						
Forward Voltage ¹	V_{SD}	-	-	-1	V	$V_{GS}=0, I_S = -1\text{A}$

Note:

1. Pulse Test : Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.
2. These parameters have no way to verify.

CHARACTERISTIC CURVES

